NSN 5961-01-349-1998

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-349-1998 **Inclosure Material:** Glass **End Application:** F-14 acft **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 forward voltage, dc **Current Rating Per Characteristic:** 1.00 microamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 25.0 degrees celsius ambient air Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli

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